

N-Channel 30-V (D-S) MOSFET

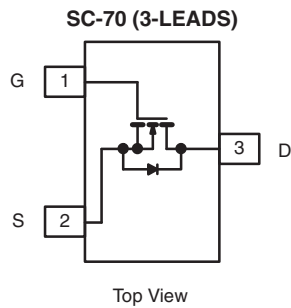
PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
30	0.480 at $V_{GS} = 10$ V	0.64
	0.700 at $V_{GS} = 4.5$ V	0.53

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC



RoHS
COMPLIANT
HALOGEN
FREE
Available



Marking Code



Lot Traceability and Date Code

Part # Code

Ordering Information: Si1302DL-T1-E3 (Lead (Pb)-free)
Si1302DL-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)					
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage	V_{DS}	30		V	
Gate-Source Voltage	V_{GS}	± 20			
Continuous Drain Current ($T_J = 150$ °C) ^a	I_D	$T_A = 25$ °C	0.64	0.60	A
		$T_A = 70$ °C	0.51	0.48	
Pulsed Drain Current	I_{DM}	1.5		A	
Continuous Diode Current (Diode Conduction) ^a	I_S	0.26	0.23		
Maximum Power Dissipation ^a	P_D	$T_A = 25$ °C	0.31	0.28	W
		$T_A = 70$ °C	0.20	0.18	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	R_{thJA}	$t \leq 5$ s	355	400	°C/W
		Steady State	380	450	
Maximum Junction-to-Foot (Drain)	R_{thJF}	285	340		

Notes:

a. Surface mounted on 1" x 1" FR4 board.

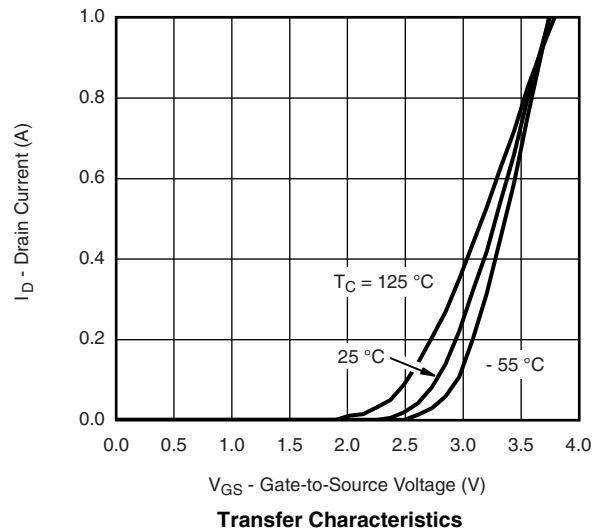
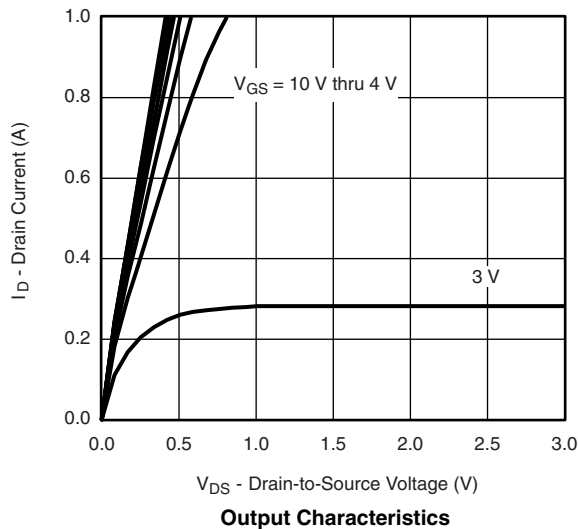
SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1		3	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V			1	μA
		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 70 °C			5	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	1.5			A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 0.6 A		0.410	0.480	Ω
		V _{GS} = 4.5 V, I _D = 0.2 A		0.600	0.700	
Forward Transconductance ^a	g _{fs}	V _{GS} = 15 V, I _D = 0.6 A		0.75		S
Diode Forward Voltage ^a	V _{SD}	I _S = 0.23 A, V _{GS} = 0 V		0.8	1.2	V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 0.6 A		0.86	1.4	nC
Gate-Source Charge	Q _{gs}			0.24		
Gate-Drain Charge	Q _{gd}			0.08		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 15 V, R _L = 30 Ω I _D ≅ 0.5 A, V _{GEN} = 10 V, R _g = 6 Ω		5	10	ns
Rise Time	t _r			8	15	
Turn-Off Delay Time	t _{d(off)}			8	15	
Fall Time	t _f			7	15	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 0.23 A, di/dt = 100 A/μs		15	30	

Notes:

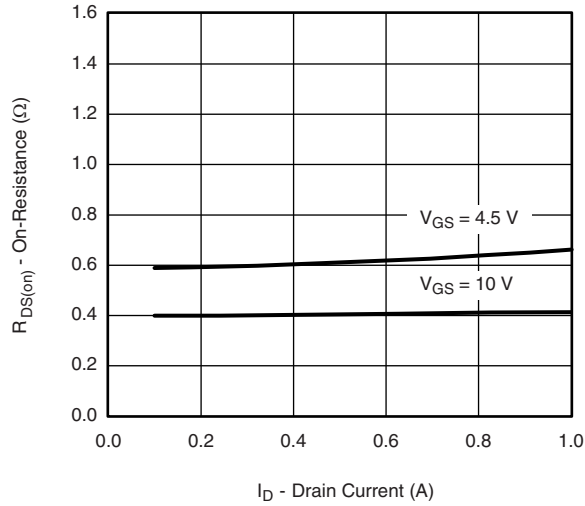
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

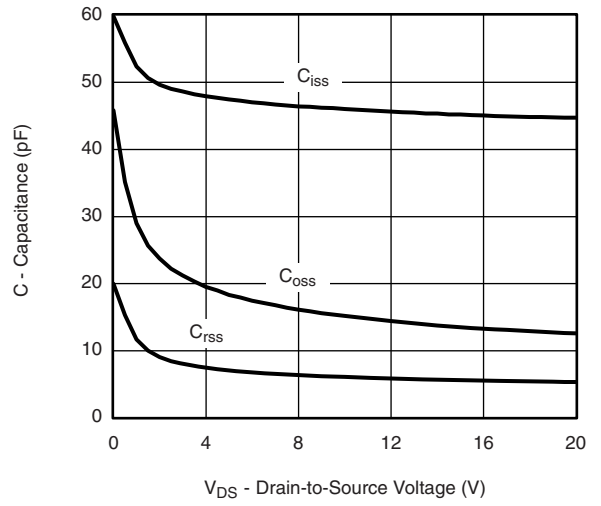
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



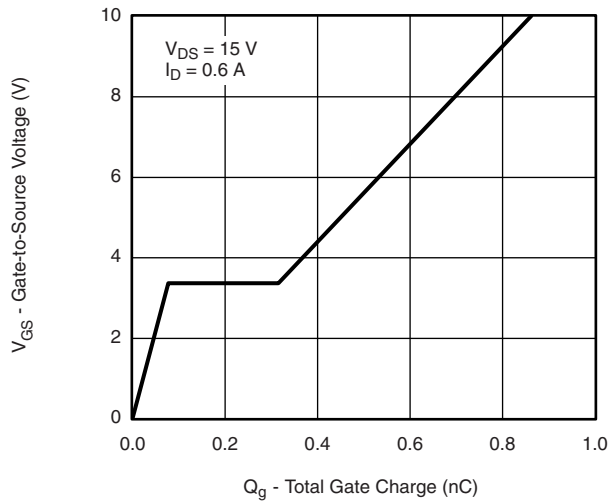
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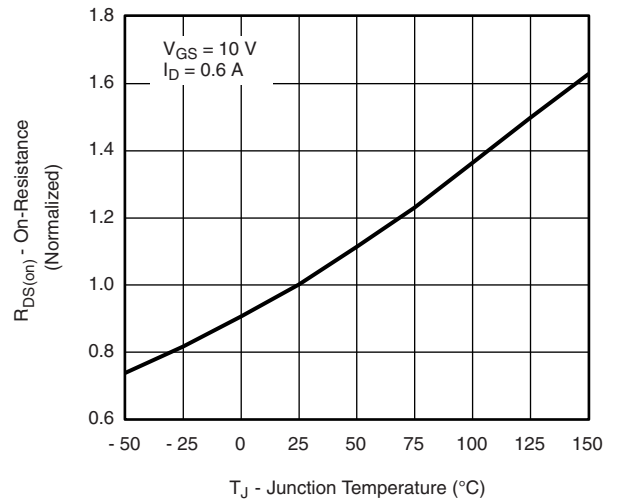
On-Resistance vs. Drain Current



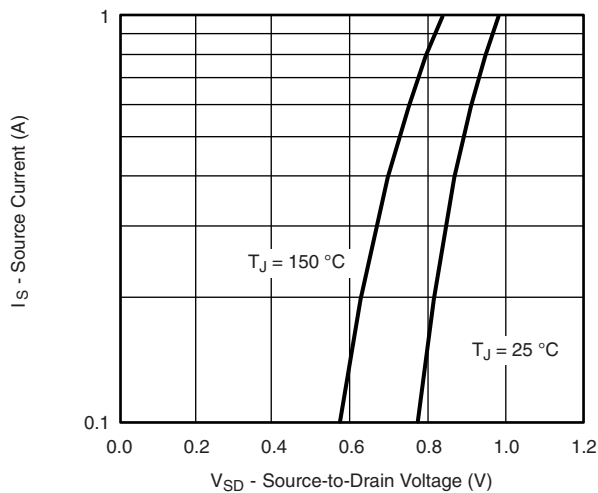
Capacitance



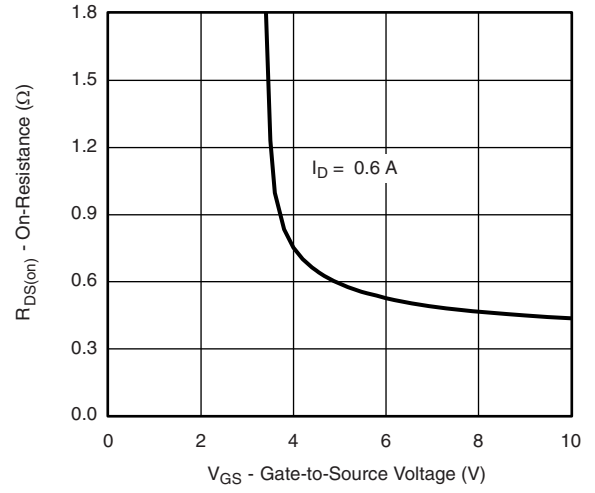
Gate Charge



On-Resistance vs. Junction Temperature

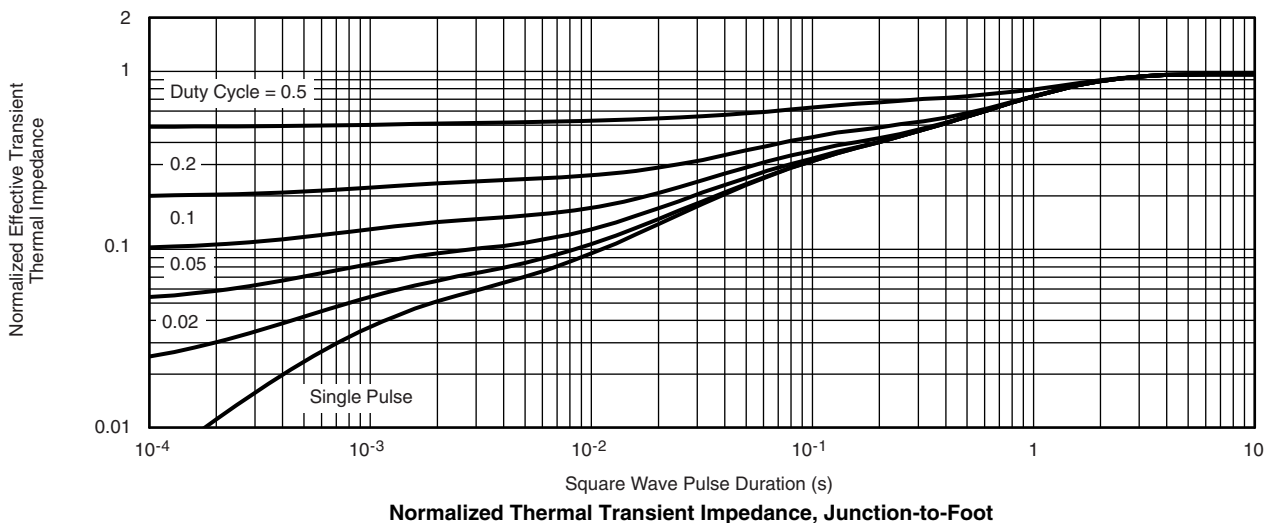
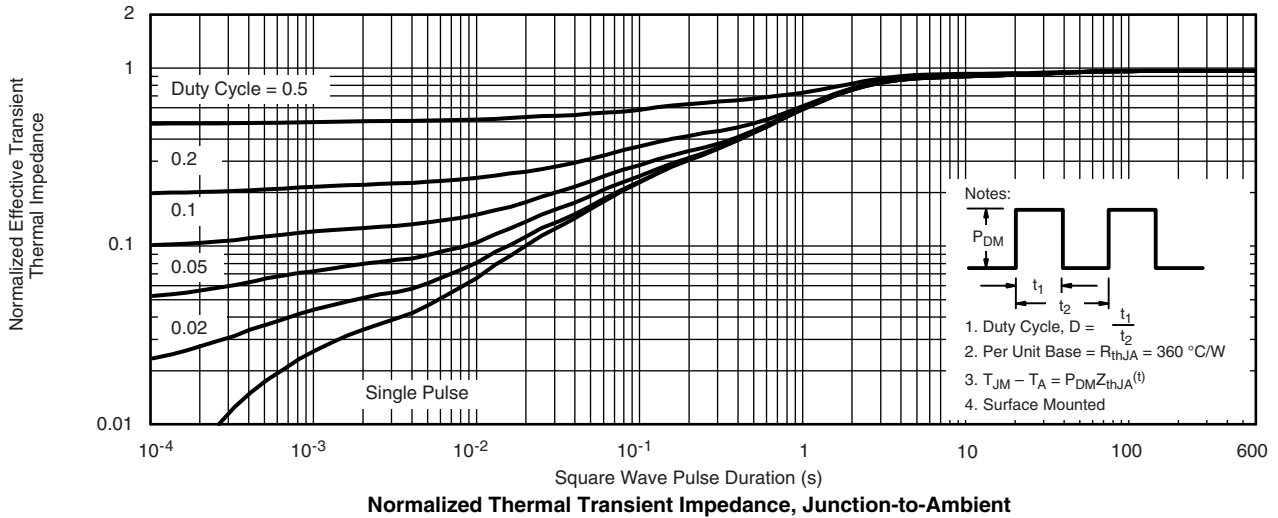
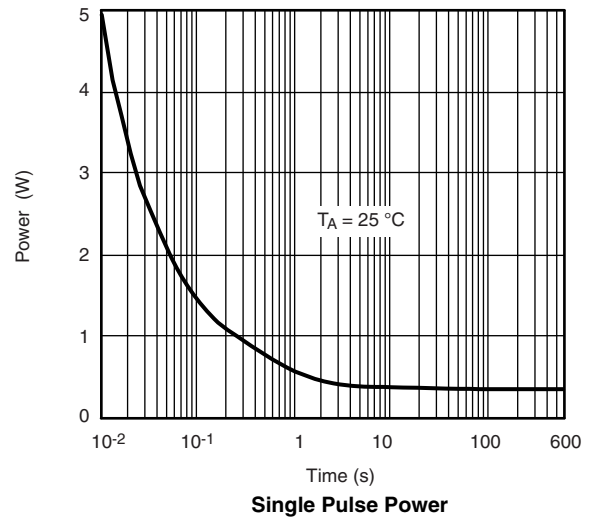
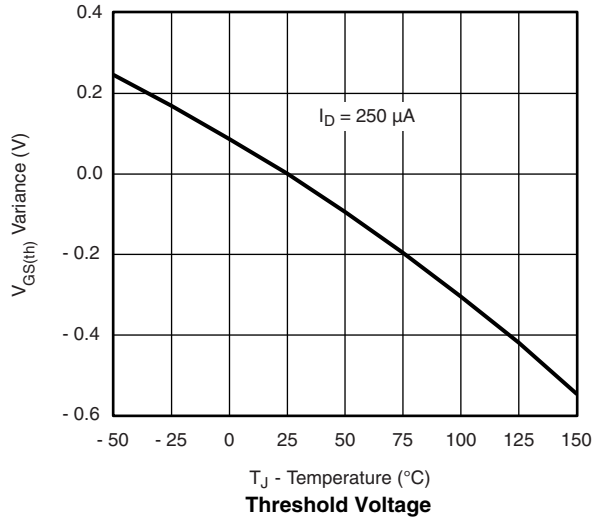


Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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